Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-884-2216

Gla	SS
Ove	erall Length:
0.2	50 inches
Ter	minal Length:
1.0	00 inches
Ove	erall Diameter:
0.0	85 inches
Мо	unting Method:
Ter	minal
Fea	atures Provided:
Her	metically sealed case
Ser	niconductor Material:
Silio	con
Vol	tage Rating In Volts Per Characteristic:
50.0	0 reverse voltage, peak
Cu	rrent Rating Per Characteristic:
3.0	0 microamperes forward current, average peak
Ma	ximum Operating Tempurature Per Measurement Point:
175	5.0 degrees celsius ambient air
Ter	minal Type And Quantity:
2 u	ninsulated wire lead
She	elf Life:
N/a	
Uni	it Of Measure:
Der	nilitarization:
No	
Fiig	j:
A11	10a0